

Sheet 1 of 1

Form PTO-1449 (REV. 8-83)		US Dept. of Commerce PATENT & TRADEMARK OFFICE		ATTY DOCKET NO. 116916			APPLICATION NO. 10/644,989			
INFORMATION DISCLOSURE STATEMENT										
(Use several sheets if necessary)				APPLICANT(S) Takamitsu HIGUCHI et al.						
				FILING DATE August 21, 2003			GROUP 2818			
U.S. PAT				ENT DOCUMENTS						
EXAMINER INITIAL		DOCUMENT NUMBER	DA1	E	NAME	3		CLASS	SUB CLASS	
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		OTHER DOCUMENTS (Include	ling A	uthor,	Title, Date, Pertinent Page	es, etc.)			•	
<b>∨</b> 0	A	Pignolet A., et al., "Large Area Pulsed Laser Deposition of Aurivillus-type Layered Perovskite Thin Films", Ferrorelectrics, Overseas Publishers Associations, Amsterdam, NL,, Vol. 202, No. 1-4, 1997, pp. 285-298.								
DV	В	Mechin L. et al., "A combined x-ray specular reflectivity and spectroscopic ellipsometry study of CeO <sub>2</sub> /yttria-stabilized-zirconia bilayers on Si(100) substrates", Journal of Applied Physics, American Institute of Physics, New York, US, Vol. 84, No. 9, 1 November 1998, pp. 4935-4940.								
D.V	С	Matthee T., et al., "Orientation relationships of epitaxial oxide buffer layers on silicon (100) for high-temperature superconducting Yba2Cu307-x films", Applied Physics Letters USA, Vol. 61, No. 10, 7 September 1992, pp. 1240-1242.								
EXAMINER		DATE CONSIDERED 09/45/05								
Examiner: In	itial if	f citation considered, whether or not citatiance and not considered. Include copy of the				609; draw			ion if not in	

Date: February 11, 2005